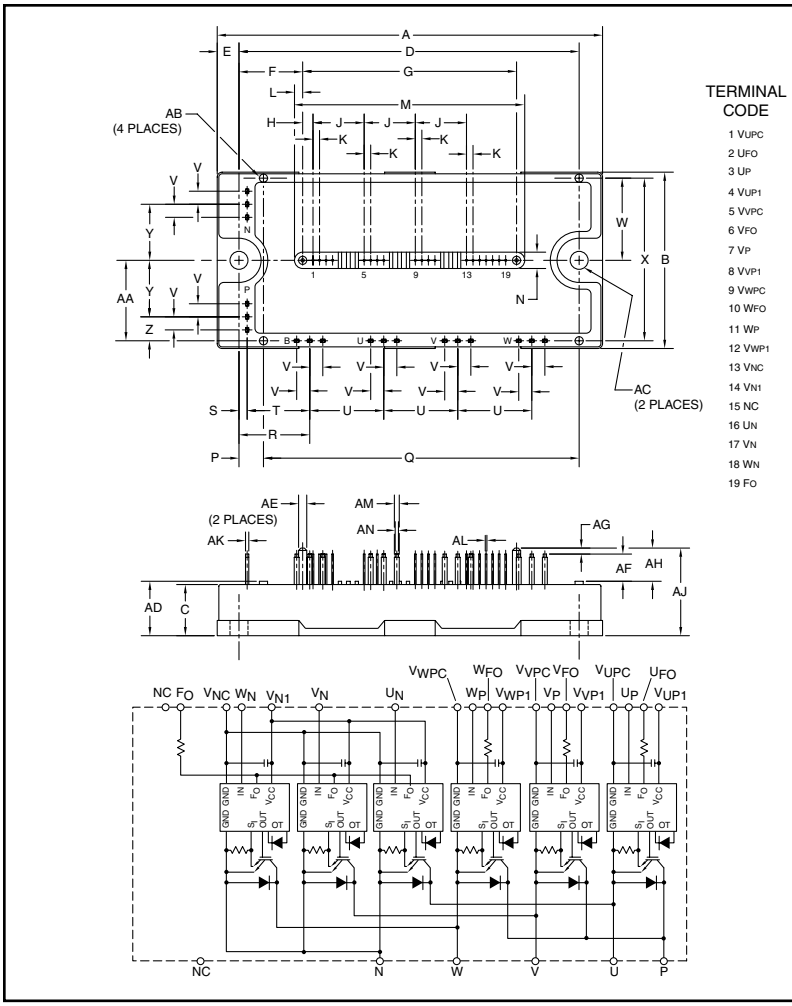
PM50CLB120

Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

Intellimod™ L-Series

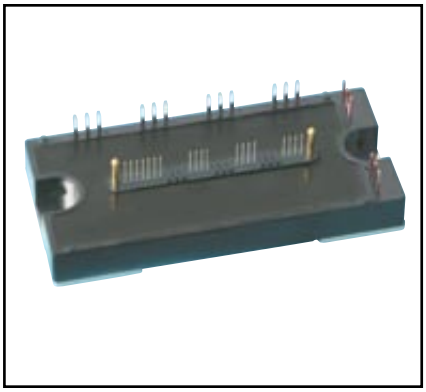
Three Phase
IGBT Inverter
50 Amperes/1200 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.72	120.0
B	2.17	55.0
C	0.63	16.0
D	4.17	106.0
E	0.28	7.0
F	0.78	19.75
G	2.62	66.5
H	0.13	3.25
J	0.63	16.0
K	0.08	2.0
L	0.10	2.5
M	2.81	71.5
N	0.20	5.0
P	0.31	7.75
Q	3.87	98.25
R	0.87	22.0
S	0.10	2.5
T	0.77	19.5
U	0.91	23.0

Dimensions	Inches	Millimeters
V	0.16	4.0
W	1.01	25.75
X	2.00	50.75
Y	0.69	17.5
Z	0.30	7.5
AA	0.98	25.0
AB	0.10 Dia.	Dia. 2.5
AC	0.22 Dia.	Dia. 5.5
AD	0.67	17.0
AE	0.10 Dia.	Dia. 2.5
AF	0.33	8.5
AG	0.08	2.0
AH	0.41	10.5
AJ	1.08	27.5
AK	0.04	1.0
AL	0.02 Sq.	Sq. 0.5
AM	0.06	1.5
AN	0.04	1.0



Description:

Powerex Intellimod™ Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:

- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Temperature Using On-chip Temperature Sensing
  - – Under Voltage
- ☐ Low Loss Using 5th Generation IGBT Chip

Applications:

- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. PM50CLB120 is a 1200V, 50 Ampere Intellimod™ Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	50	120

Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

Characteristics	Symbol	PM50CLB120	Units
Power Device Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Mounting Torque, M5 Mounting Screws	—	31	in-lb
Module Weight (Typical)	—	340	Grams
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	1000	Volts
Self-protection Supply Voltage Limit (Short Circuit protection Capability)*	$V_{CC(prot.)}$	800	Volts
Isolation Voltage, AC 1 minute, 60Hz Sinusoidal	V_{ISO}	2500	Volts

*VD = 13.5 ~ 16.5V, Inverter Part, Tj = 125°C

IGBT Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	1200	Volts
Collector Current (T_C = 25°C)	$\pm I_C$	50	Amperes
Peak Collector Current (T_C = 25°C)	$\pm I_{CP}$	100	Amperes
Collector Dissipation (T_C = 25°C)	P_C	369	Watts

Control Sector

Supply Voltage (Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between U_{FO}-V_{UPC}, V_{FO}-V_{VPC}, W_{FO}-V_{WPC}, F_O-V_{NC})	V_{FO}	20	Volts
Fault Output Current (U_{FO}, V_{FO}, W_{FO}, F_O Terminals)	I_{FO}	20	mA

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Cutoff Current	I_{CES}	V_{CE} = V_{CES}, V_D = 15V, T_j = 25°C	—	—	1.0	mA
		V_{CE} = V_{CES}, V_D = 15V, T_j = 125°C	—	—	10	mA
Diode Forward Voltage	V_{EC}	-I_C = 50A, V_{CIN} = 15V, V_D = 15V	—	2.5	3.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 50A, T_j = 25°C	—	1.8	2.3	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 50A, T_j = 125°C	—	1.9	2.4	Volts
Inductive Load Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 15V V_{CC} = 600V, I_C = 50A T_j = 125°C	0.5	1.0	2.5	µs
	t_{rr}		—	0.5	0.8	µs
	$t_{C(on)}$		—	0.4	1.0	µs
	t_{off}		—	2.0	3.0	µs
	$t_{C(off)}$		—	0.7	1.2	µs

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Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Short Circuit Trip Level	SC	-20°C ≤ T_j ≤ 125°C, V_D = 15V	100	—	—	Amperes
Short Circuit Current Delay Time	$t_{off(SC)}$	V_D = 15V	—	0.2	—	µs
Over Temperature Protection	OT	Trip Level	135	145	155	°C
(Detect T_j of IGBT Chip)	OT_R	Reset Level	—	125	—	°C
Supply Circuit Under-voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
(-20 ≤ T_j ≤ 125°C)	UV_R	Reset Level	—	12.5	—	Volts
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	—	15	25	mA
		V_D = 15V, V_{CIN} = 15V, V_{XP1}-V_{XPC}	—	5	10	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied between U_P-V_{UPC},	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-V_{NC}	1.7	2.0	2.3	Volts
Fault Output Current*	$I_{FO(H)}$	V_D = 15V, V_{CIN} = 15V	—	—	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{CIN} = 15V	—	10	15	mA
Fault Output Pulse Width*	t_{FO}	V_D = 15V	1.0	1.8	—	ms

*Fault output is given only when the internal SC, OT and UV protections schemes of either upper or lower devide operate to protect it.

Thermal Characteristics

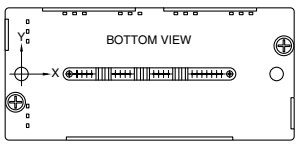
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	IGBT (Per 1/6 Module)	—	—	0.26	°C/Watt
	$R_{th(j-c)D}$	FWDi (Per 1/6 Module)	—	—	0.39	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.038	°C/Watt

Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	≤800	Volts
Control Supply Voltage**	V_D	Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC}	15.0 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P-V_{UPC},	≤0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$	V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-V_{NC}	≥9.0	Volts
PWM Input Frequency	f_{PWM}	—	≤20	kHz
Arm Shoot-through Blocking Time	t_{DEAD}	Input Signal	≥2.5	µs

** With ripple satisfying the following conditions: dv/dt swing ≤ ±5V/µs, Variation ≤ 2V peak to peak.

T_C Measurement Point



Arm / Axis	UP		VP		WP		UN		VN		WN	
	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi
X	28.3	28.4	65.0	64.9	87.0	86.9	39.3	39.2	54.0	54.1	76.0	76.1
Y	-7.7	1.5	-7.7	1.5	-7.7	1.5	5.7	-3.5	5.7	-3.5	5.7	-3.5

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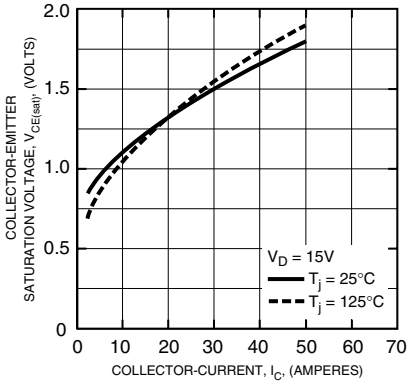
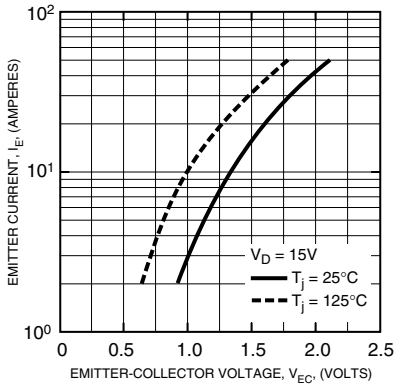
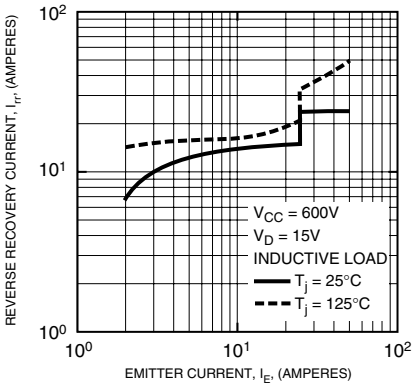
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)



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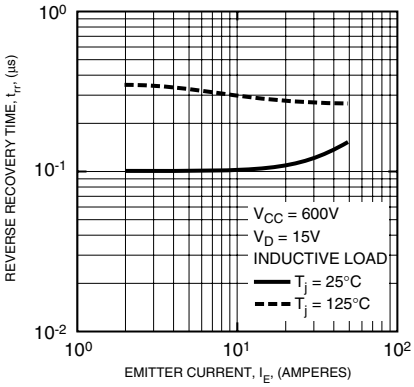
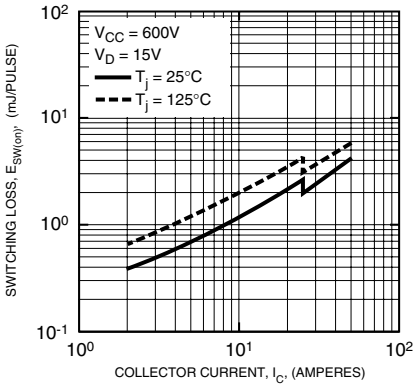
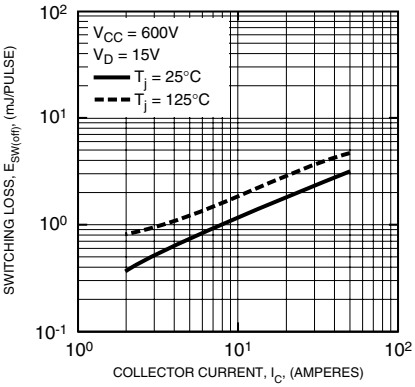


SWITCHING LOSS (ON) VS. COLLECTOR CURRENT (TYPICAL)



SWITCHING LOSS (OFF) VS. COLLECTOR CURRENT (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT & FWDi)